

Compact, high-sensitive 1.5 megapixel color Bayer global shutter image sensor



Order code	Description
VD66GYCCA/RW	Color Bayer, bare die as reconstructed wafer

Features

- Cutting-edge performance of ST proprietary pixel:
 - BSI structure provides superior QE, MTF, and angular response.
 - Full DTI technology further increases sensitivity and sharpness.
 - Excellent response across the whole color spectrum.
 - Proprietary technology from ST foundry in France, ensuring safe supply.
- Easy integration into your system:
 - Ultracompact die with centered design to minimize your system size.
 - Small optical format: 4.6 mm (1/4") at full resolution and 3.7 mm (1/5") with 1 MP crop.
 - Low power, ideal for battery-powered devices.
 - Robust design and image quality in temperature.
- A complete toolbox of in-sensor features:
 - Stunning images with in-sensor autoexposure and various corrections.
 - Multiple features to optimize data size and frame rates such as crop, binning, and programmable sequences.
 - 8 GPIOs enabling extra controls such as trigger or LED synchronization.
- Seamless connection to embedded processing platforms:
 - 1 or 2 lanes MIPI CSI-2 interface enabling straight connection to entrylevel cost-effective processing platforms.
 - Start immediately your development with our turnkey sensor boards, modules, and drivers for the VD66GY image sensor.
- The VD66GY color image sensor is also available in monochrome (VD56G3) and RGB-NIR versions (VD16GZ).

Description

The VD66GY is part of a brand-new complete series of image sensors developed by STMicroelectronics for professional and consumer vision applications. Leveraging state-of-the-art technologies developed by STMicroelectronics own foundry, the sensor provides outstanding performance enabling to capture bright and sharp color images. With its clever design and complete toolbox of on-chip functions, it is the ideal solution for the design of tomorrow's smart and optimized systems.

Application

- Home and service robots
- Smart appliances
- AR/VR and gaming
- Drones and UAVs
- Industrial robots and AGVs
- · Quality inspection
- 3D stereo imaging
- Barcode reading, logistics and retail
- Security and biometrics



Acronyms and abbreviations

Table 1. Acronyms and abbreviations

Acronym/abbreviation	Definition	
ADC	analog to digital converter	
AE	autoexposure	
AGV	automated guided vehicle	
AR	augmented reality	
CCI	camera control interface	
СР	charge pump	
CRA	chief ray angle	
CSI	camera serial interface	
DTI	deep trench isolation	
EMC	electromagnetic compatibility	
EMI	electromagnetic interference	
FoV	field of view	
fps	frames per second	
GPIO	general-purpose input/output	
I ² C	inter-integrated circuit (bus)	
ISL	intelligent status line	
ISP	image signal processor	
LDO	low dropout regulator	
LED	light-emitting diode	
MCU	microcontroller unit	
MIPI	mobile industry processor interface	
MTF	modulation transfer function	
NIR	near infrared	
OIF	output interface	
OTP	one-time programmable	
PLL	phase-locked loop	
PWM	pulse-width modulation	
QE	quantum efficiency	
RI	relative illumination	
SW	software	
UAV	unmanned aerial vehicle	
UI	user interface for host to sensor communication	
VR	virtual reality	

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2 Product overview

2.1 Functional description summary

The VD66GY is a 1.5-megapixel global shutter image sensor featuring a matrix of 1124 x 1364 pixels. With its global shutter operation, all pixels are synchronized to capture light at the same time. This removes the motion blur that can affect rolling shutter image sensors, when capturing changing or moving scenes.

Once the exposure is finished, each pixel information is transferred in a storage node, before being read and digitized one pixel row after the other. The image data are digitized using internal 10-bit ADCs. Additional gains can be applied before ADC stage (for example, analog gain) or after ADC stage (for example, digital gain). Following the digital conversion, various image preprocessing and correction algorithms can be applied into the sensor before data output, such as autoexposure or binning.

The image data are output as frames of RAW8 or RAW10 data through a MIPI CSI-2 interface. The sensor can be configured to operate with either 1 or 2 MIPI CSI-2 lanes to best fit with host processing requirements.

The VD66GY is synchronized to the rest of the system by means of an external clock, triggers, and general-purpose input/output (GPIO) signals that can be used to enable synchronization of several sensor readouts or to control strobe light sources during exposure time.

The device is fully configurable through the I²C serial interface and provides flexible frame-to-frame parameter configuration changes via the use of programmable contexts. It also embeds a one-time programmable (OTP) non-volatile memory to be written by 32-bit words.

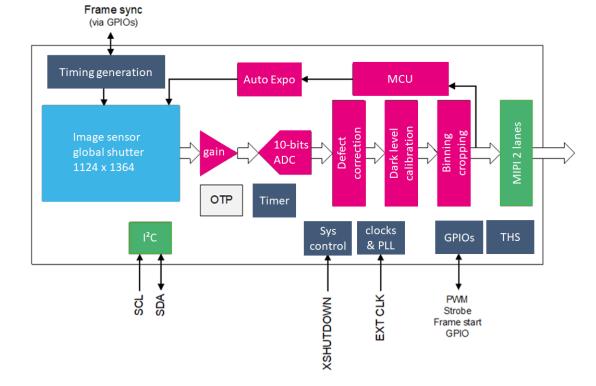


Figure 1. Functional block diagram

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2.2 Technical specifications summary

Table 2. Technical specifications

Category	Parameter	VD66GY specifications	
	Resolution	1.53 MP	
Resolution	Pixel array [H x V]	1124 x 1364	
	Aspect ratio	5:6	
	Shutter type	Global shutter	
Pixel	Illumination type	Back side illuminated	
	Pixel size	2.61 µm	
Color	Color option	Color Bayer	
	Full resolution	88 fps	
Frame rates (maximum)	1 MP resolution	121 fps	
	VGA resolution	237 fps	
	Pixel array size [H x V]	2.93 mm x 3.56 mm	
Optical characteristics	Optical format	1/4" (4.61 mm)	
	CRA	30° linear	
	Die footprint [H x V]	3.65 mm x 4.34 mm	
Mechanical characteristics	Die centering (optical vs. mechanical)	Yes	
	Die pinout	115 pins	
	Operating temperature range	-30 to +85°C	
	Sensor data interface	MIPI CSI-2 1 or 2 lanes (1)	
	Sensor control interface	I ² C, up to 1 Mbit/s/s	
	Output format	RAW8, RAW10	
Electronic characteristics	Supply voltages	2.8 V – 1.8 V – 1.15 V	
	External clock frequency	6 to 27 MHz	
	Power consumption	120 mW (typical) 4 mW (standby)	
	Image quality optimization	 Autoexposure Automatic dark calibration Defective pixel correction Analog gain Digital gains (independent for each color channel) Binning 	
Embedded features	Data and frame rate optimization	 Cropping Binning Subsampling Context management with up to 4 contexts 	
	Others	 Mirror/Flip Test pattern generation Temperature sensor 8 programmable GPIOs for LED control, PWM control, and leader or follower external frame start (2) 	

^{1.} MIPI = mobile industry processor interface and CSI = camera serial interface.

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^{2.} GPIO = general-purpose input/output, LED = light emitting diode, and PWM = pulse width modulation.



3 Functional description

3.1 Interfaces

3.1.1 Inter-integrated circuit (I²C)

The VD66GY is configured and controlled via an I²C interface operating in either fast mode (up to 400 kHz) or fast mode plus (up to 1 MHz) at 1.8 V. After the MCU boot sequence, the default I²C configuration is fast mode plus with a sink capability set to 20 mA. Drive capability can be decreased to 4 mA (fast mode) by writing a dedicated register once the system has booted. Device addressing uses a CCI protocol with 2 byte subaddresses. The default sensor address is 0x20 (including R/W bit), and can be overridden:

- Permanently by storing a non-null value in a dedicated OTP register.
- Dynamically with a firmware command when the MCU state is SW_STANDBY.

3.1.2 Camera serial interface (CSI)

The sensor is ready to connect via a dual lane mobile industry processor interface (MIPI) CSI-2 serial interface.

The dual lane MIPI CSI-2 serial interface supports up to 1.5 Gbps per lane. It is the industry standard for low electromagnetic interference (EMI) and excellent electromagnetic compatibility (EMC) high-speed interfacing. The CSI lane number can be lowered to a single lane. Resolution is scalable between RAW8 and RAW10.

3.2 Power supplies

The power supplies required by the sensor are:

- 2.8 V for the analog blocks
- 1.8 V for the digital I/Os
- 1.15 V for the core digital logic and MIPI CSI-2 output drivers

The pixel array requires different positive and negative voltages, all internally generated by charge pumps and regulators. Four voltage references, internally generated, need external decoupling capacitors. The internal MCU handles the entire power management of the sensor to guarantee the lowest power consumption at any given time

3.3 Clock and PLL

An input clock is required from an external digital clock source in the range of 6 to 27 MHz. Firmware is preconfigured for a 12 MHz external source clock. Two built-in PLL (phase-locked loop) blocks generate all necessary internal clocks for the pixel array, processing pipe, and output interface.

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3.4 Video pipe

The video pipe performs several features designed to ensure a high quality image. These features include:

- Analog subsampling
- Pattern generation
- Dynamic defective pixel correction
- Dark calibration
- Autoexposure
- Digital binning
- Embedded status lines
- Output interface
- Context management
- Cropping

The diagram below presents the features implementation in the video pipe

Resolution x1/4 or x1

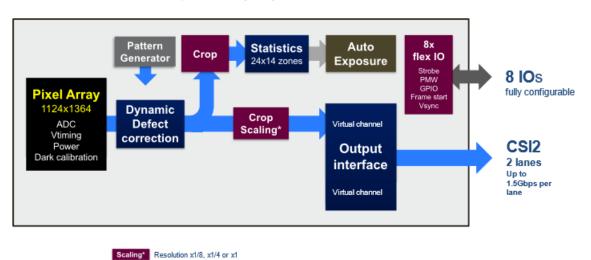


Figure 2. Image signal processor schematic

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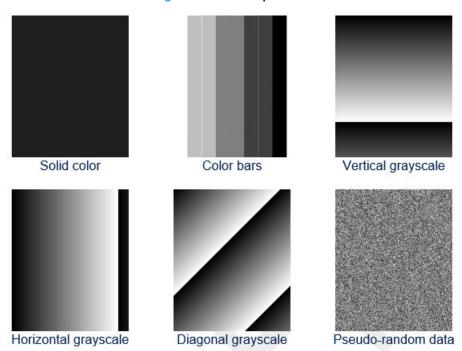


3.4.1 Pattern generation

The pattern generation allows the generation of digital patterns in the output frame for test and debug. It is also possible to insert a cross bar in the image with configurable position, size, and brightness. The available patterns are:

- Solid color
- Color bars
- Vertical grayscale
- Horizontal grayscale
- · Diagonal grayscale
- Pseudo-random data

Figure 3. Available patterns



3.4.2 Defective pixel correction

Active pixels are automatically corrected by a dynamic algorithm embedded in the sensor ISP, enabling defectfree images straight out of the sensor without further algorithm development or processing resources.

The advanced correction algorithm can correct singlet and couplet of defects and take into account local spatial gradients.

The host can program the strength of the correction to find the perfect balance between systematic defect correction and preserving existing textures/patterns in the image. The correction strength evolves automatically with exposure time. This mechanism can be deactivated for debugging purposes and for specific use cases such as structured light.

3.4.3 Dark calibration

The pixel matrix has dedicated lines with shielded pixels that dynamically retrieve the dark level and subtract it from the active image. Temperature, exposure time, or gain changes are compensated. Temporal smoothing and fractional bit dithering are applied to avoid a sudden one-code step. This block also embeds a programmable digital gain control feature with a granularity of 1/256 followed by a configurable pedestal to offset the dark level along the ISP pipe.

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3.4.4 Analog and digital gains

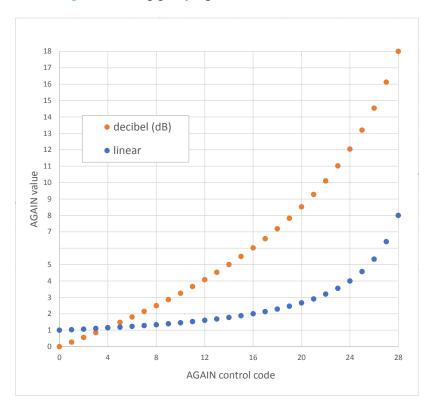
The VD66GY enables to adjust analog and digital gains on the image to optimize image quality depending on the lighting conditions. Gains are adjusted automatically when autoexposure is enabled, or by manual control when autoexposure is disabled.

Analog gain ranges from x1 (+ 0 dB) up to x8 (+18 dB) with 29 steps following a 1/X behavior enabling to benefit from fine gain granularity at low gain and wider granularity at high gains to better adjust image quality. It follows the following formula:

Analog
$$gain(x) = \frac{32}{32-x}$$

Where x is an integer from 0 to 28.

Figure 4. Analog gain progression versus control code



Four digital gains (one per color channel) can be applied, each of them ranging from 1.0 up to 8.0 minus one step control with a step control of 1/256th so approximately 0.0039.

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3.4.5 Autoexposure

The autoexposure (AE) feature computes and automatically applies the ideal exposure time and gain factors to get the optimum average luminance in the image. The autoexposure algorithm is performed directly in the sensor, to benefit from automatic exposure without the need to develop any dedicated algorithm or to allocate processor resources to the computation.

The sensor can also operate in manual mode where exposure parameters are provided by the host.

The host can configure autoexposure module parameters that control brightness target, convergence speed, and stability. The region of interest (ROI) used for autoexposure can be set independently from the image capture region.

A specific antiflickering mode can be selected to mitigate artifacts introduced by ambient light frequency and frame rate differences.

A dedicated I²C status register provides the image average brightness information when the sensor is set to autoexposure or manual exposure mode. This information is also available in the status lines (ISL) embedded at the beginning of each frame. Refer to Section 3.4.8: Embedded status lines for ISL description.

3.4.6 Analog subsampling

The devices support x2 and x4 subsampling which reduces overall image size and keeps the same field of view (FoV). Subsampling is applied vertically and horizontally during the ADC readout, where every two or every four pixels are read. When subsampling is used, the frame rate can be increased by decreasing the frame length.

3.4.7 Digital binning

The digital binning process reduces the image resolution by a factor of 2 or 4 in each direction. Central and neighboring pixels are weighted to produce the digital binned image, avoiding special phase shift and artifacts which may occur on the output image. Digital binning and subsampling are mutually exclusive.

3.4.8 Embedded status lines

The output interface (OIF) embeds the intelligent status line generator, which allows metadata to be sent through the MIPI image data interface. The ISL follows the SMIA CSI-2, simplified, 2-byte, tagged data format for RAW8 data packing. There are two ISL lines transmitted at the beginning of each frame. Each data packet is 256 bytes long. The length of the ISL can be stretched to equal the active line packet size.

The MCU has access to a bank of status registers, refreshed at each frame, and providing detailed information on the current state of the sensor. Most of the content of this bank is also available in ISLs. The ISL contains all information related to the current transmitted frame such as:

- Clock settings
- Cropping and orientation parameters
- Analog and digital gains
- Integration time
- Frame counter index
- Thermal sensor values
- Dark calibration parameters

Transmission of ISL data packets can be disabled by configuring a static register during SW_STANDBY state before streaming. ISL data packets have their own programmable "data types" and "virtual channels".

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3.4.9 Output interface

The output interface (OIF) embeds two data lanes of the MIPI D-PHY interface. It supports up to 1.5 Gbps of data per lane. The OIF outputs active pixel data in RAW10 or RAW8.

The OIF can output a combination of the following:

- Intelligent status lines
- Active pixel data

The OIF supports multiple virtual channels and different data types for active pixels and ISL data.

3.4.10 Context management

The sensor allows the configuration of up to four different rolling contexts (or frame setups). Parameters that can be specifically defined in a context are listed in the figure below.

Contexts (4x) Context n°3 Context n°2 Context n°1 Context n°0 - Exposure mode - Analog gain - Digital gain - Coarse exposure - Frame length - Y start & end - Output ROI - GPIOs - Readout mode - Number of frames per setup - Next Context - Delay for next Context

Figure 5. Context parameters

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Contexts can be chained one to another in an ending or non-ending sequence.

Flexible sequences Start of frame Start of frame 7x frames 1x frame Next context n°3 Next context n°3 1x frames 4x frames Next context n°1 Next context n°1 Wait before next 15x frames Next context n°2 4x frames 1
Next context none 8x frames Next context n°3 Mode idle

Figure 6. Example of ending and non-ending multicontext sequence

3.4.11 Cropping

The host can accurately choose which area of the whole pixel array it receives. This reduces traffic on the CSI interface and saves processing time.

3.4.12 Orientation

The sensor image can be horizontally (mirror) and/or vertically flipped, as illustrated in the following figure.

Figure 7. Image orientation



Horizontal and vertical

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Vertical



3.5 Synchronization modes

The sensor has multiple synchronization modes:

- 1. Leader mode
 - Image streaming starts right after the execution of a streaming initialization command sent over the I²C bus
 - After the initialization sequence, wait for a rising edge event on GPIO0 to start streaming images
- 2. Follower mode
 - Using GPIO pulses
 - Using I²C triggering commands

3.6 General purpose input/outputs (GPIOs)

The sensor provides eight GPIOs:

- GPIO0 is used as a frame start synchronization signal or as a generic GPIO if not used for this function
- GPIO[1-7] are used as PWM outputs, pulse (strobe) outputs, VSYNC, or as a generic GPIO, as per the configuration

Pulse

Vsync

GPIO

oto 7

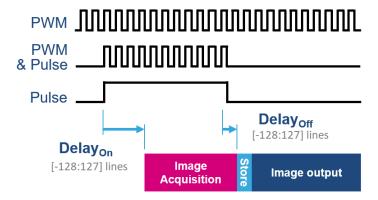
GPIO

pin

Figure 8. GPIO modes

All GPIO settings are fully configurable for the four context setups. Each output signal can be mapped to one or several of the GPIOs. All GPIOs have configurable polarity.

Figure 9. PWM and pulse overview



During SW_STANDBY state the GPIOs can be controlled as output low/high or input.

Start*
*Only for GPIO 0

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3.7 Sensor firmware

The sensor is presenting to the host a user interface (bank of registers), accessible via the I²C bus.

The host writes high-level parameters in the user interface and an MCU inside the sensor applies the proper sensor configuration based on UI settings provided by the host.

3.8 Use case examples

Table 3. Example of functional use cases

Resolution	Maximum fps	Typical data rate	
1124 x 1364	. 1364 88 2 lanes, 800 Mbps per lane		
1124 x 1364	88	1 lane, 1500 Mbps	
720 x 1280	90	2 lanes, 800 Mbps per lane	
640 x 480	210	1 lane at 1500 Mbps	
320 x 240	360	1 lane at 1500 Mbps	

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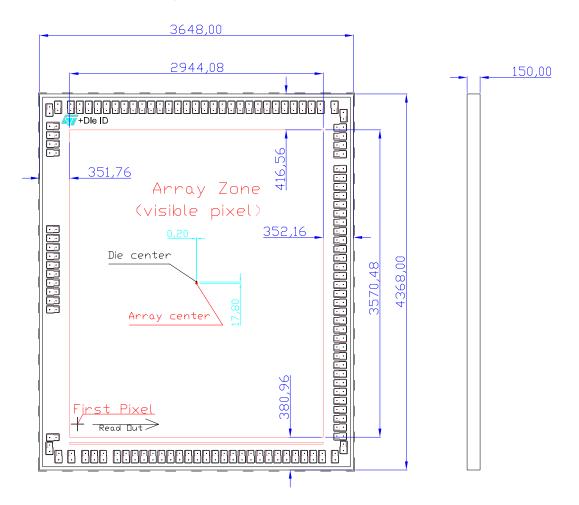
4 Die specification

In the table below, the die dimensions are after sawing.

Table 4. Die dimensions

Description	North, (+y) μm	East, (+x) μm	South, (-y) μm	West, (-x) μm
Chip center	0.0	0.0	0.0	0.0
Optical center	_	-0.2	-17.80	_
First active pixel	1767.44	1471.84	-1803.04	-1472.24
First µlens	_	_	_	_
Inner edge of pad	2025.9	1665.9	-2025.9	-1665.9
Center of pad	2065.9	1705.9	-2065.9	-1705.9
Edge of chip	2184 ±10	1824 ±10	-2184 ±10	-1824 ±10
1/2 scribe width	50.0	50.0	50.0	50.0

Figure 10. Die mechanical dimensions (µm)



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Pin description and assignment

Table 5. Pin description

Pin name	Туре	Description	Reset state	Reference supply			
VCORE		1.15 V power supply for the digital core		1.15 V			
VDDIO		1.8 V power supply for IOs		1.8 V			
VANA	PWR	2.8 V analog power supply		2.8 V			
DGND		Digital ground		VDDIO			
AGND	-	Analog ground		VANA			
Reference							
LDO2V4		Internal reference (must be connected together)					
VCPNEG_IN		Must be connected to VCPNEG_OUT					
VCPNEG_OUT		Must be connected to VCPNEG_IN		VANA			
VCPPOS_IN	REF	Must be connected to VCPPOS_OUT					
VCPPOS_OUT		Must be connected to VCPPOS_IN					
VDDAMP		All VDDAMP (internal reference) must be connected together		VDDIO			
		CSI-2 interface					
DATA1P, DATA1N		CSI-2 data lane 1, positive and negative					
DATA2P, DATA2N	MIPI DPHY	CSI-2 data lane 2, positive and negative	Low	VCORE			
CLKP, CLKN		CSI-2 clock, positive and negative					
		Host interface					
XSHUTDOWN	I	Reset active low					
SDA	Ю	I ² C data					
SCL	I	I ² C clock					
GPIO0							
GPIO1							
GPIO2				VDDIO			
GPIO3	10	Consumb market 1/O and stucks limbs control	1	VDDIO			
GPIO4	IO	General-purpose I/O and strobe light control	Low				
GPIO5							
GPIO6							
GPIO7							
CLKIN	I	Input clock					
		Other pins					
PORTEST	I	Must be connected to digital ground		VDDIO			
NC		Not connected					
RCALIB		Not connected					

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Table 6. Pin coordinates

The pin coordinates (0, 0) are the die center

Pin number	Bonding point X coordinate	Bonding point Y coordinate	Net name	
1	-1611.62	2065.9	VCPPOS_OUT	
2	-1461.56	2065.9	VANA	
3	-1357.52	2065.9	AGND	
4	-1253.97	2065.9	DGND	
5	-1150.42	2065.9	VCORE	
6	-1046.87	2065.9	AGND	
7	-943.32	2065.9	DGND	
8	-839.77	2065.9	VCORE	
9	-736.22	2065.9	VANA	
10	-632.67	2065.9	VANA	
11	-529.12	2065.9	AGND	
12	-425.57	2065.9	VCORE	
13	-322.02	2065.9	NC	
14	-218.47	2065.9	VANA	
15	-114.92	2065.9	NC	
16	-11.37	2065.9	AGND	
17	92.18	2065.9	VANA	
18	195.73	2065.9	DGND	
19	299.28	2065.9	VCORE	
20	402.83	2065.9	DGND	
21	506.38	2065.9	VANA	
22	609.93	2065.9	AGND	
23	713.48	713.48 2065.9		
24	817.03	2065.9	AGND	
25	920.62	2065.9	DGND	
26	1024.17	2065.9	DGND	
27	1127.77	2065.9	SDA	
28	1231.32	2065.9	SCL	
29	1334.87	2065.9	VCORE	
30	1438.42	2065.9	XSHUTDOWN	
31	1600.34	2065.9	VDDIO	
32	1705.9	1969.53	NC	
33	1705.9	1798.29	GPIO0	
34	1705.9	1694.72	PORTST	
35	1705.9	1591.15	DGND	
36	1705.9	1487.58 GPIO1		
37	1705.9	1316.29 GPIO2		
38	1705.9	1212.71 DGND		
39	1705.9	1109.14	VCORE	
40	1705.9	1005.58	DGND	

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Pin number	Bonding point X coordinate	Bonding point Y coordinate	Net name
41	1705.9	902	VCORE
42	1705.9	798.44	DGND
43	1705.9	694.87	LDO2V4
44	1705.9	591.29	VCORE
45	1705.9	487.73	DGND
46	1705.9	384.16	VDDIO
47	1705.9	280.58	GPIO3
48	1705.9	177.02	VCORE
49	1705.9	73.44	DGND
50	1705.9	-30.13	GPIO4
51	1705.9	-133.69	NC
52	1705.9	-237.26	VCORE
53	1705.9	-340.83	DGND
54	1705.9	-444.41	DGND
55	1705.9	-547.98	DGND
56	1705.9	-651.54	VCORE
57	1705.9	-755.12	AGND
58	1705.9	-858.69	GPIO5
59	1705.9	-962.25	GPIO6
60	1705.9	-1065.83	GPIO7
61	1705.9	-1169.39	VDDIO
62	1705.9	-1272.96	VANA
63	1705.9	-1376.54	LDO2V4
64	1705.9	-1480.11	DGND
65	1705.9	-1583.67	VCORE
66	1705.9	-1687.25	DGND
67	1705.9	-1790.82	CLKIN
68	1705.9	-1959.03	VDDIO
69	1611.63	-2065.9	DGND
70	1461.52	-2065.9	DGND
71	1357.95	-2065.9	VDDAMP
72	1254.38	-2065.9	VCORE
73	1150.81	-2065.9	DGND
74	1047.24	-2065.9	DGND
75	943.67	-2065.9	DATA2N
76	840.1	-2065.9	DATA2P
77	736.53	-2065.9	VDDAMP
78	78 632.96 -2065.9		CLKN
79	529.39	-2065.9	DGND
80	425.82	-2065.9	CLKP
81	322.25	-2065.9	VCORE

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82 218.68 -2065.9 VDDAMP 83 115.11 -2065.9 DATAIN 84 11.54 -2065.9 DATAIP 85 -92.03 -2065.9 DGND 86 -195.6 -2065.9 LDOZV4 87 -299.17 -2065.9 VDDAMP 88 -402.74 -2065.9 DGND 89 -506.31 -2065.9 DGND 90 -609.88 -2065.9 VCORE 91 -713.45 -2065.9 AGND 92 -817.02 -2065.9 NC 94 -1081.63 -2065.9 NC 94 -1081.63 -2065.9 AGND 95 -1185.2 -2065.9 AGND 96 -1288.77 -2065.9 VCORE 98 -1601.12 -2065.9 VCORE 98 -1601.12 -2065.9 VCORE 99 -1705.9 -1808.5 VCPNEG_IN 100	Pin number	Bonding point X coordinate	Bonding point Y coordinate	Net name	
84 11.54 -2065.9 DATA1P 85 -92.03 -2065.9 DGND 86 -195.6 -2065.9 LDO2V4 87 -299.17 -2065.9 VDDAMP 88 -402.74 -2065.9 RCALIB 89 -506.31 -2065.9 DGND 90 -609.88 -2065.9 VCORE 91 -713.45 -2265.9 AGND 92 -817.02 -2065.9 AGND 93 -920.59 -2065.9 NC 94 -1081.63 -2065.9 NC 95 -1185.2 -2065.9 DGND 96 -1288.77 -2065.9 VCORE 98 -1601.12 -2065.9 VCORE 98 -1601.12 -2065.9 VANA 99 -1705.9 -1808.5 VCPNEG_IN 100 -1705.9 -321.68 VCPNEG_IN 101 -1705.9 -218.11 AGND 103 <td>82</td> <td>218.68</td> <td>-2065.9</td> <td>VDDAMP</td>	82	218.68	-2065.9	VDDAMP	
85 .92.03 .2065.9 DGND 86 .195.6 .2065.9 LDO2V4 87 .299.17 .2065.9 VDDAMP 88 .402.74 .2065.9 RCALIB 89 .506.31 .2065.9 DGND 90 .609.88 .2065.9 VCORE 91 .713.45 .2065.9 AGND 92 .817.02 .2065.9 AGND 93 .920.59 .2065.9 NC 94 .1081.63 .2065.9 NC 95 .1185.2 .2065.9 DGND 96 .1288.77 .2065.9 VCORE 98 .1601.12 .2065.9 VCORE 98 .1601.12 .2065.9 VCNE 98 .1601.12 .2065.9 VCNE 99 .1705.9 .1808.5 VCPNEG_IN 100 .1705.9 .1808.5 VCPNEG_IN 101 .1705.9 .218.11 AGND 103 </td <td>83</td> <td>115.11</td> <td colspan="2">115.11 -2065.9</td>	83	115.11	115.11 -2065.9		
86 -195.6 -2065.9 LDO2V4 87 -299.17 -2065.9 VDDAMP 88 -402.74 -2065.9 RCALIB 89 -506.31 -2065.9 DGND 90 -609.88 -2065.9 VCORE 91 -713.45 -2065.9 AGND 92 -817.02 -2065.9 AGND 93 -920.59 -2065.9 NC 94 -1081.63 -2065.9 NC 95 -1185.2 -2065.9 DGND 96 -1288.77 -2065.9 VCORE 98 -1601.12 -2065.9 VCORE 98 -1601.12 -2065.9 VANA 99 -1705.9 -1969.53 AGND 100 -1705.9 -1808.5 VCPNEG_IN 101 -1705.9 -218.11 AGND 102 -1705.9 -141.54 DGND 103 -1705.9 -11.45.4 DGND 104 <td>84</td> <td colspan="2">11.54 -2065.9</td> <td>DATA1P</td>	84	11.54 -2065.9		DATA1P	
87 -299.17 -2065.9 VDDAMP 88 -402.74 -2065.9 RCALIB 89 -506.31 -2065.9 DGND 90 -609.88 -2065.9 VCORE 91 -713.45 -2065.9 AGND 92 -817.02 -2065.9 AGND 93 -920.59 -2065.9 NC 94 -1081.63 -2065.9 NC 95 -1185.2 -2065.9 DGND 96 -1288.77 -2065.9 VCORE 98 -1601.12 -2065.9 VCORE 98 -1601.12 -2065.9 VANA 99 -1705.9 -1969.63 AGND 100 -1705.9 -1808.5 VCPNEG_IN 101 -1705.9 -321.68 VCPNEG_OUT 102 -1705.9 -218.11 AGND 103 -1705.9 -114.54 DGND 104 -1705.9 -10.97 VANA 10	85	-92.03	-2065.9	DGND	
88 -402.74 -2065.9 RCALIB 89 -506.31 -2065.9 DGND 90 -609.88 -2065.9 VCORE 91 -713.45 -2065.9 AGND 92 -817.02 -2065.9 AGND 93 -920.59 -2065.9 NC 94 -1081.63 -2065.9 NC 95 -1185.2 -2065.9 DGND 96 -1288.77 -2065.9 VCORE 98 -1601.12 -2065.9 VANA 99 -1705.9 -1969.53 AGND 100 -1705.9 -1808.5 VCPNEG_IN 101 -1705.9 -218.11 AGND 102 -1705.9 -218.11 AGND 103 -1705.9 -114.54 DGND 104 -1705.9 -10.97 VANA 105 -1705.9 92.6 VANA 106 -1705.9 196.17 NC 107	86	-195.6	-2065.9	LDO2V4	
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90	88	-402.74	-2065.9	RCALIB	
91 -713.45 -2065.9 AGND 92 -817.02 -2065.9 AGND 93 -920.59 -2065.9 NC 94 -1081.63 -2065.9 NC 95 -1185.2 -2065.9 DGND 96 -1288.77 -2065.9 AGND 97 -1451.06 -2065.9 VCORE 98 -1601.12 -2065.9 VANA 99 -1705.9 -1808.5 VCPNEG_IN 101 -1705.9 -218.11 AGND 103 -1705.9 -114.54 DGND 104 -1705.9 -10.97 VANA 105 -1705.9 92.6 VANA 106 -1705.9 196.17 NC 107 -1705.9 196.17 NC 108 -1705.9 196.17 NC 109 -1705.9 196.17 NC 100 -1705.9 196.17 NC 101 -1705.9 196.17 NC 102 -1705.9 196.17 NC 103 -1705.9 196.17 NC 104 -1705.9 196.17 NC 105 -1705.9 196.17 NC 106 -1705.9 196.17 NC 107 -1705.9 196.17 NC 108 -1705.9 196.17 NC 109 -1705.9 196.17 NC 110 -1705.9 196.17 NC 110 -1705.9 196.17 NC 111 -1705.9 196.18 VCPPOS_IN 112 -1705.9 1498.25 VCPPOS_IN 113 -1705.9 1498.25 VCPPOS_IN 114 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA 114 -1705.9 1705.38 VANA	89	-506.31	-2065.9	DGND	
92 -817.02 -2065.9 AGND 93 -920.59 -2065.9 NC 94 -1081.63 -2065.9 NC 95 -1185.2 -2065.9 DGND 96 -1288.77 -2065.9 AGND 97 -1451.06 -2065.9 VCORE 98 -1601.12 -2065.9 VANA 99 -1705.9 -1808.5 VCPNEG_IN 100 -1705.9 -218.11 AGND 103 -1705.9 -218.11 AGND 104 -1705.9 -218.11 AGND 105 -1705.9 -218.11 AGND 106 -1705.9 -218.11 AGND 107 -1705.9 -218.11 AGND 108 -1705.9 -218.11 NC 109 -1705.9 -206.0 VANA 106 -1705.9 -206.0 VANA 107 -1705.9 -206.0 VANA 108 -1705.9 -206.0 VANA 109 -1705.9 -206.0 VANA 100 -1705.9 -206.0 VANA 101 -1705.9 -206.0 VANA 102 -1705.9 -206.0 VANA 103 -1705.9 -206.0 VANA 104 -1705.9 -206.0 VANA 105 -1705.9 -209.74 NC 107 -1705.9 -209.74 NC 108 -1705.9 -209.74 NC 109 -1705.9 -209.74 NC 110 -1705.9 -209.74 NC 111 -1705.9 -209.74 NC 112 -1705.9 -209.74 NC 113 -1705.9 -209.74 NC 114 -1705.9 -209.74 NC 115 -1705.9 -209.74 NC 116 -1705.9 -209.74 NC 117 -1705.9 -209.74 NC 118 -1705.9 -209.74 NC 119 -1705.9 -209.74 NC 110 -1705.9 -209.74 NC 111 -1705.9 -209.74 NC 112 -1705.9 -209.74 NC 113 -1705.9 -209.74 NC 114 -1705.9 -209.74 NC 115 -2065.9 NC 116 -2065.9 NC 117 NC 118 NC 119 NC 110 NC 11	90	-609.88	-2065.9	VCORE	
93	91	-713.45	-2065.9	AGND	
94 -1081.63 -2065.9 NC 95 -1185.2 -2065.9 DGND 96 -1288.77 -2065.9 AGND 97 -1451.06 -2065.9 VCORE 98 -1601.12 -2065.9 VANA 99 -1705.9 -1808.5 VCPNEG_IN 101 -1705.9 -218.11 AGND 102 -1705.9 -218.11 AGND 103 -1705.9 -114.54 DGND 104 -1705.9 -10.97 VANA 105 -1705.9 92.6 VANA 106 -1705.9 196.17 NC 107 -1705.9 196.17 NC 108 -1705.9 196.17 NC 109 -1705.9 196.17 NC 109 -1705.9 196.17 NC 110 -1705.9 196.17 NC 110 -1705.9 196.17 NC 110 -1705.9 196.17 NC 111 -1705.9 A03.31 NC 112 -1705.9 1498.25 VCPPOS_IN 112 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA	92	-817.02	-2065.9	AGND	
95	93	-920.59	-2065.9	NC	
96 -1288.77 -2065.9 AGND 97 -1451.06 -2065.9 VCORE 98 -1601.12 -2065.9 VANA 99 -1705.9 -1969.53 AGND 100 -1705.9 -1808.5 VCPNEG_IN 101 -1705.9 -321.68 VCPNEG_OUT 102 -1705.9 -218.11 AGND 103 -1705.9 -114.54 DGND 104 -1705.9 -114.54 DGND 105 -1705.9 9-10.97 VANA 106 -1705.9 92.6 VANA 106 -1705.9 196.17 NC 107 -1705.9 196.17 NC 108 -1705.9 403.31 NC 109 -1705.9 506.88 VCORE 110 -1705.9 506.88 VCORE 110 -1705.9 1498.25 VCPPOS_IN 111 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA	94	-1081.63	-2065.9	NC	
97 -1451.06 -2065.9 VCORE 98 -1601.12 -2065.9 VANA 99 -1705.9 -1969.53 AGND 100 -1705.9 -1808.5 VCPNEG_IN 101 -1705.9 -321.68 VCPNEG_OUT 102 -1705.9 -218.11 AGND 103 -1705.9 -114.54 DGND 104 -1705.9 -114.54 DGND 105 -1705.9 92.6 VANA 106 -1705.9 92.6 VANA 106 -1705.9 196.17 NC 107 -1705.9 196.17 NC 108 -1705.9 403.31 NC 109 -1705.9 506.88 VCORE 110 -1705.9 506.88 VCORE 111 -1705.9 1498.25 VCPPOS_IN 112 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA	95	-1185.2	-2065.9	DGND	
98 -1601.12 -2065.9 VANA 99 -1705.9 -1969.53 AGND 100 -1705.9 -1808.5 VCPNEG_IN 101 -1705.9 -321.68 VCPNEG_OUT 102 -1705.9 -218.11 AGND 103 -1705.9 -114.54 DGND 104 -1705.9 -10.97 VANA 105 -1705.9 92.6 VANA 106 -1705.9 196.17 NC 107 -1705.9 196.17 NC 108 -1705.9 403.31 NC 109 -1705.9 506.88 VCORE 110 -1705.9 610.45 AGND 111 -1705.9 1498.25 VCPPOS_IN 112 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA	96	-1288.77	-2065.9	AGND	
99 -1705.9 -1969.53 AGND 100 -1705.9 -1808.5 VCPNEG_IN 101 -1705.9 -321.68 VCPNEG_OUT 102 -1705.9 -218.11 AGND 103 -1705.9 -114.54 DGND 104 -1705.9 -10.97 VANA 105 -1705.9 92.6 VANA 106 -1705.9 196.17 NC 107 -1705.9 196.17 NC 108 -1705.9 403.31 NC 109 -1705.9 506.88 VCORE 110 -1705.9 506.88 VCORE 110 -1705.9 1498.25 VCPPOS_IN 111 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA	97	-1451.06	-2065.9	VCORE	
100 -1705.9 -1808.5 VCPNEG_IN 101 -1705.9 -321.68 VCPNEG_OUT 102 -1705.9 -218.11 AGND 103 -1705.9 -114.54 DGND 104 -1705.9 -10.97 VANA 105 -1705.9 92.6 VANA 106 -1705.9 196.17 NC 107 -1705.9 299.74 NC 108 -1705.9 403.31 NC 109 -1705.9 506.88 VCORE 110 -1705.9 610.45 AGND 111 -1705.9 1498.25 VCPPOS_IN 112 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA 114 -1705.9 1808.95 AGND	98	-1601.12	-2065.9	VANA	
101 -1705.9 -321.68 VCPNEG_OUT 102 -1705.9 -218.11 AGND 103 -1705.9 -114.54 DGND 104 -1705.9 -10.97 VANA 105 -1705.9 92.6 VANA 106 -1705.9 196.17 NC 107 -1705.9 299.74 NC 108 -1705.9 403.31 NC 109 -1705.9 506.88 VCORE 110 -1705.9 610.45 AGND 111 -1705.9 1601.82 VCPPOS_IN 112 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA 114 -1705.9 1808.95 AGND	99	-1705.9	-1969.53	AGND	
102 -1705.9 -218.11 AGND 103 -1705.9 -114.54 DGND 104 -1705.9 -10.97 VANA 105 -1705.9 92.6 VANA 106 -1705.9 196.17 NC 107 -1705.9 299.74 NC 108 -1705.9 403.31 NC 109 -1705.9 506.88 VCORE 110 -1705.9 610.45 AGND 111 -1705.9 1601.82 VCPPOS_IN 112 -1705.9 1705.38 VANA 114 -1705.9 1808.95 AGND	100	-1705.9	-1808.5	VCPNEG_IN	
103 -1705.9 -114.54 DGND 104 -1705.9 -10.97 VANA 105 -1705.9 92.6 VANA 106 -1705.9 196.17 NC 107 -1705.9 299.74 NC 108 -1705.9 403.31 NC 109 -1705.9 506.88 VCORE 110 -1705.9 610.45 AGND 111 -1705.9 1498.25 VCPPOS_IN 112 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA 114 -1705.9 1808.95 AGND	101	-1705.9	-321.68	VCPNEG_OUT	
104 -1705.9 -10.97 VANA 105 -1705.9 92.6 VANA 106 -1705.9 196.17 NC 107 -1705.9 299.74 NC 108 -1705.9 403.31 NC 109 -1705.9 506.88 VCORE 110 -1705.9 610.45 AGND 111 -1705.9 1498.25 VCPPOS_IN 112 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA 114 -1705.9 1808.95 AGND	102	-1705.9	-218.11	AGND	
105 -1705.9 92.6 VANA 106 -1705.9 196.17 NC 107 -1705.9 299.74 NC 108 -1705.9 403.31 NC 109 -1705.9 506.88 VCORE 110 -1705.9 610.45 AGND 111 -1705.9 1498.25 VCPPOS_IN 112 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA 114 -1705.9 1808.95 AGND	103	-1705.9	-114.54	DGND	
106 -1705.9 196.17 NC 107 -1705.9 299.74 NC 108 -1705.9 403.31 NC 109 -1705.9 506.88 VCORE 110 -1705.9 610.45 AGND 111 -1705.9 1498.25 VCPPOS_IN 112 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA 114 -1705.9 1808.95 AGND	104	-1705.9	-10.97	VANA	
107 -1705.9 299.74 NC 108 -1705.9 403.31 NC 109 -1705.9 506.88 VCORE 110 -1705.9 610.45 AGND 111 -1705.9 1498.25 VCPPOS_IN 112 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA 114 -1705.9 1808.95 AGND	105	-1705.9	92.6	VANA	
108 -1705.9 403.31 NC 109 -1705.9 506.88 VCORE 110 -1705.9 610.45 AGND 111 -1705.9 1498.25 VCPPOS_IN 112 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA 114 -1705.9 1808.95 AGND	106	-1705.9	196.17	NC	
109 -1705.9 506.88 VCORE 110 -1705.9 610.45 AGND 111 -1705.9 1498.25 VCPPOS_IN 112 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA 114 -1705.9 1808.95 AGND	107	-1705.9	299.74	NC	
110 -1705.9 610.45 AGND 111 -1705.9 1498.25 VCPPOS_IN 112 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA 114 -1705.9 1808.95 AGND	108	-1705.9	403.31	NC	
111 -1705.9 1498.25 VCPPOS_IN 112 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA 114 -1705.9 1808.95 AGND	109	-1705.9	506.88	VCORE	
112 -1705.9 1601.82 VCORE 113 -1705.9 1705.38 VANA 114 -1705.9 1808.95 AGND	110	-1705.9	610.45	AGND	
113 -1705.9 1705.38 VANA 114 -1705.9 1808.95 AGND	111	-1705.9	1498.25	VCPPOS_IN	
114 -1705.9 1808.95 AGND	112	112 -1705.9 1601.82		VCORE	
	113	-1705.9	1705.38		
115 -1705.9 1959.04 VANA	114			AGND	
	115	-1705.9	1959.04	VANA	

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6 Application schematic

6.1 Additional components

Dedicated additional capacitors are required to complete the circuit. These are listed in Table 7. Capacitor needs below. The capacitors should be selected to maintain their capacitance value within the indicated tolerance over the full range of maximum voltages, operating temperatures, and aging.

Capacitor values are based on capacitor positions (embedded in the camera module or external to the camera module).

External capacitors are required to properly filter out supply noise. Optimal reference in terms of value and size is subject to application board architecture and topology. The external capacitor values provided in the table below may be increased to compensate real supply noise.

Table 7. Capacitor needs

Associated pin name	Capacitor position	Typical voltage	Minimum capacitance	Typical capacitance	Maximum capacitance	Operating frequencies	Capacitor ground	Purpose
CPPOS_IN, CPPOS_OUT	Embedded	3.55 V	330 nF	470 nF	560 nF	160 MHz	AGND	CP tank capacitor
CPNEG_IN, CPNEG_OUT	Embedded	-2.0 V	650 nF	0.88 μF	1.04 µF	160 MHz	AGND	CP tank capacitor
VDDIO	Embedded	1.8 V				1 MHz	DGND	Supply
VDDIO	External	1.0 V	1 μF			I WII IZ	DGND	decoupling
	Embedded		470 nF			800 MHz 1 GHz - 1.5	DGND	Supply decoupling
VCORE	External	1.15 V	10 μF			GHz 160 MHz - 200 MHz	DGND	Supply decoupling
VANA	Embedded	2.8 V	100 nF			160 MHz	AGND	Supply
VAINA	External	2.0 V	10 μF			TOU WITZ	AGND	decoupling
LDO2V4	Embedded	2.4 V	100 nF		1 μF	DC	AGND	LDO capacitor
VDDAMP	Embedded	1.15 V	100 nF		1 µF	1.5 GHz	DGND	Supply decoupling

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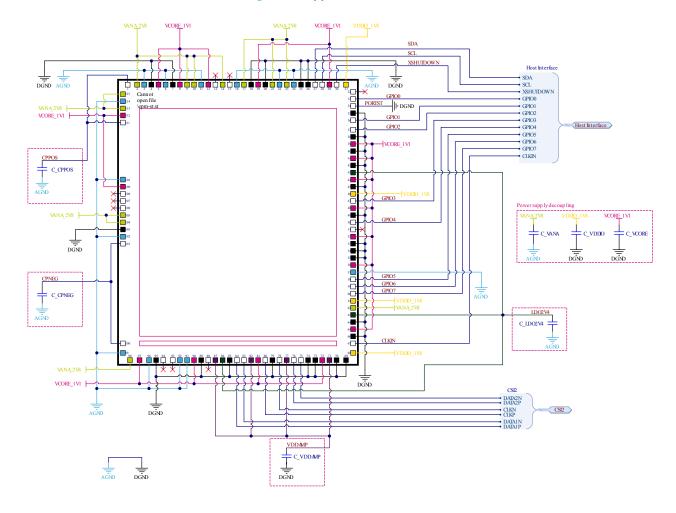


Figure 11. Application schematic

6.2 Layout guidelines

For good PCB design practice, observe the following image sensor layout:

- Use power and ground planes to supply power to the sensor.
- Join grounds i.e. join AGND and DGND into one single, solid GND plane underneath the sensor.
- Connect this GND plane to the sensor pins with one via per GND pin.
- To minimize risk of emissions, shield all vias and tracks attached to supplies by their respective GND nets.
- Maximize copper fill on the power planes near the sensor and use vias to improve heat transfer from the sensor. Consider including additional heatsinks close to the sensor if it is to be used at high temperatures.
- Route the high-speed signal pairs of the MIPI CSI-2 interface with balanced and controlled impedance differential traces (50 Ω single-ended impedance, 100 Ω differential impedance). This is a requirement for high-speed signaling. Route each pair together and match them in length to target a maximum 10 ps skew.

VCPNEG_IN and VCPNEG_OUT must be connected together with a short track. The required decoupling capacitor shall be placed on this path and not on an isolated track.

VCPPOS_IN and VCPPOS_OUT must be connected together with a short track. The required decoupling capacitor shall be placed on this path and not on an isolated track.

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6.3 Device power up sequence

To power on the device:

- Provide all the external supplies (VCORE, VDDIO, VANA) according to the device characteristics described in Section 8: Electrical characteristics. As long as XSHUTDOWN is low, the device is in HW_STANDBY state.
- You can switch on the external supplies and CLKIN in any order.
- Set XSHUTDOWN to high.

Figure 12. Power up sequence



The device has power-on-reset (POR) detection cells with hysteresis on VCORE and VDDIO power supplies. POR is released after a typical delay of 20 µs on the rising edge.

Bursts with a duration of less than 2 µs (typical) are ignored.

Table 8. POR typical threshold

Supply	POR typical threshold rising edge (V)	POR typical threshold falling edge (V)
VCORE	0.65	0.55
VDDIO	1.1	0.95

6.4 Device power down sequence

The power down sequence must be done as follows:

- If the sensor is in STREAMING state, then set it to SW_STANDBY state and wait for the command to complete.
- 2. Set XSHUTDOWN to low.
- 3. External supplies can be switched off in any order, as well as CLKIN.

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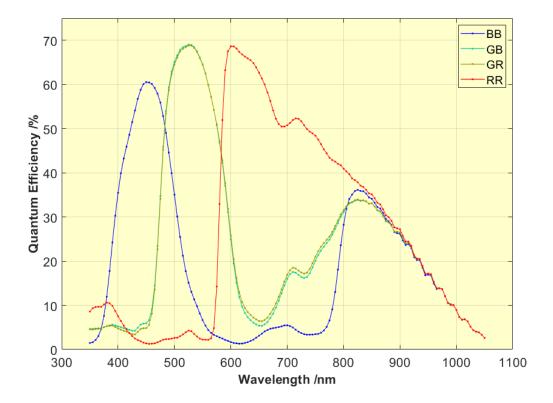
7 Pixel performance

The information listed in this section is for typical parts at ambient temperature (Tj = 40°C).

7.1 Quantum efficiency

Each color pixel captures a certain wavelength range of visible light. They are respectively centered in the red range, in the green range and in the blue range. Quantum efficiency (QE) is the percentage of incident photons converted into electrons, representing the sensitivity of this color pixel.





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7.2 MTF

The modulation transfer function (MTF) measures the ability of the device to differentiate spatial frequencies. The MTF value represents the contrast restitution for the corresponding spatial frequency, hence describes the contrast attenuation. It is a sharpness indicator that quantifies to what extent the image sensor can capture and discriminate tiny detailed contrast of an object in the field of view.

The figure below presents the on-axis MTF, measured in a 100x28 pixels ROI with the slanted-edge method. Note that in the following figure, Ny is the spatial Nyquist frequency.

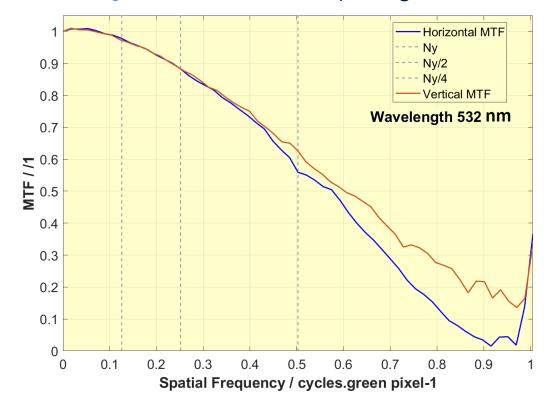


Figure 14. On-axis vertical and horizontal pixel MTF @ 532 nm

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7.3 Color pattern

The VD66GY is a color image sensor featuring a classic 2x2 Bayer pattern, which is composed of red, green and blue pixels as illustrated in the figure below. This pattern enables host processors to extrapolate the frames of RAW data output by the VD66GY into an RGB colored image

(0,0)
GRRRGRRRBBGBBBGBGRRRGRRRBBGBBBGB

Figure 15. VD66GY 2x2 pattern

7.4 Microlenses and CRA matching

Each pixel of the matrix has its own microlens covering it.

The purpose of the microlens is to concentrate and optimize photon capture by passing through the module lens down to the photo diode to increase sensor light sensitivity and to maximize the amount of light received by each pixel.

The light beam has an incidence angle change when passing through the module lens, increasing from center to periphery. This is the chief ray angle (CRA).

To compensate for the change of CRA over the matrix, the microlens position over the pixels progressively shifts from matrix center to matrix borders.

The design of the sensor microlens shift is optimized for matching a lens with CRA of 30° at corners and follows a linear shift shape.

It is recommended to match the CRA of the lens with the CRA of the image sensor to maximize image quality. Featuring advanced BSI pixel technology, the VD66GY provides high relative illumination (RI) uniformity up to the image corners, which enables users to select lenses with different CRA with limited impact.

The following figure presents the CRA tolerance range in lens selection for maintaining a RI uniformity over 90% across the image.

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Figure 16. Guideline for lens CRA matching

Sensor micro lens shift and lens CRA tolerance (10% RI loss) versus distance to center

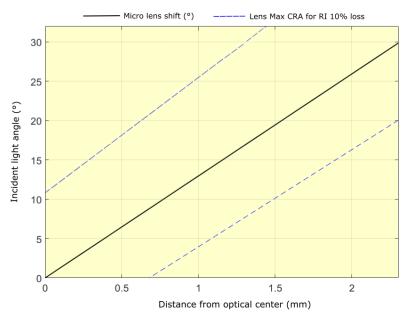
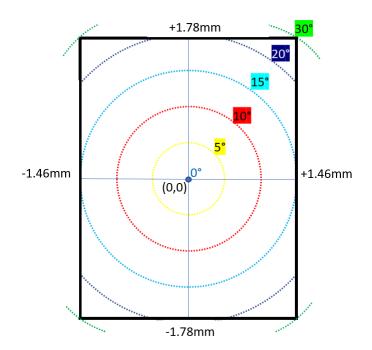


Figure 17. Co-centric pixel microlens CRA shift



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8 Electrical characteristics

The electrical characteristics have been measured under the following typical conditions:

- Full resolution (1124 x 1364)
- 60 fps
- Nominal power supply levels
- External clock at 12 MHz
- Junction temperature at 60°C
- Nominal voltage

8.1 Absolute maximum ratings

Caution:

Stresses above those listed under "Absolute maximum ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 9. Absolute maximum ratings

Symbol	Parameter	Max	Unit
VDDIO	Digital IO power supply	2.5	V
VANA	Analog power supply	3.5	V
VCORE	Digital core power supply	1.4	V
VIO	IO referenced to VDDIO	2.5	V
VESD, electrostatic discharge	Human body model (HBM)	±2	kV
model	Charge device model (CDM)	±500	V

8.2 Operating conditions

Table 10. Operating conditions

Symbol	Parameter	Min.	Тур.	Max.	Unit
VDDIO	Digital IO power supply	1.7	1.8	1.9	
VANA	Analog power supply	2.65	2.8	2.95	V
VCORE	Digital core power supply	1.08	1.15	1.26	V
VIO	IO referenced to VDDIO	-0.3	_	VDDIO + 0.3	
		Tempe	erature		
T JF	Junction temperature (functional operation)	-30	_	85	°C

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8.3 Power consumption

Table 11. Typical power consumption

Values below are measured for the conditions listed in Section 8: Electrical characteristics, but they also include process variability.

State	VDDI	VDDIO (nominal)		VCORE (nominal)		VANA (nominal)		Unit	Total power				
State	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Ullit	Тур.	Max.	Unit
Reset	0.0075	0.013	0.017	0.2	2.1	6.5	0.028	0.038	0.05		2.5	_	
SW_STANDBY	0.0075	0.013	0.017	1	3.3	7.5	0.028	0.043	0.05		4	_	
Streaming image 60 fps	7.5	8.5	11.0	50	57	65	18	22.8	25	mA	145	_	mW
Leader mode 30 fps	_	6.8	_	_	49.5	_	_	17.4	_		120	_	
Follower mode 0 fps	_	5.5	_	_	43	_	_	13.5	_		97	_	

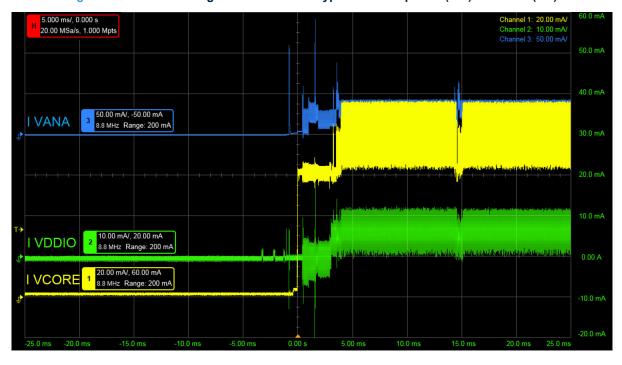
Table 12. Maximum supply consumption

Values below are measured for the worst conditions of process, voltage, and temperature.

State	VDDIO (mA)	VCORE (mA)	VANA (mA)
SW_STANDBY	0.02	23	0.1
Streaming image 60 fps	11	86	25

8.3.1 Current profile

Figure 18. Start streaming and first frame of typical current profile (mA) over time (ms)



Note: Figure 18. Start streaming and first frame of typical current profile (mA) over time (ms) is captured at maximum temperature and voltage.

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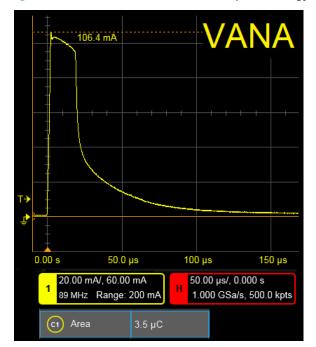


Figure 19. Detail of VANA first transient pulse energy

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8.4 CLKIN input

Table 13. Typical CLKIN input

The CLKIN input is for all voltage and temperature conditions.

Symbol	Parameter	Min.	Max.	Unit
V _{CLKINL}	DC-coupled square wave low-level input	-0.3	0.3 x VDDIO	\ \/
V _{CLKINH}	DC-coupled square wave high-level input	0.7 x VDDIO	VDDIO + 0.3	V
f _{CLKIN}	Clock input frequency	6	27	MHz
CtoCjitter	Clock maximum cycle-to-cycle jitter	_	200	ps
Duty cycle	Clock duty cycle	40	60	%
I _{CLKIN}	Input leakage current	_	10	μA

8.5 Digital inputs

Table 14. Digital inputs over process variations at 60°C

Symbol	Parameter	Min.	Max.	Unit
V _{IL}	Low-level input voltage	-0.3	0.3 x VDDIO	V
V _{IH}	High-level input voltage	0.7 x VDDIO	VDDIO + 0.3	V
I _{Leak}	Input leakage current (1)	_	10	μA

^{1.} For $0 \le VI \le VDDIO$

8.6 Digital outputs

Table 15. Digital outputs

The digital outputs are over process variations at 60°C.

Symbol	Parameter	Conditions	Min.	Max.	Unit
V _{OL}	Low-level output voltage	IOL = -4 mA	_	0.4	V
V _{OH}	High-level output voltage	IOH = 4 mA	VDDIO - 0.4V	_	V
I _{max}	Maximum current	_	_	4	mA

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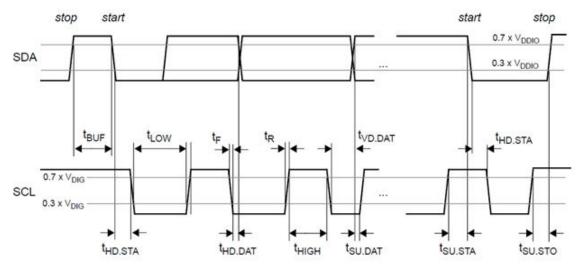
8.7 I²C interface - SDA, SCL

Table 16. I²C timing

The values below are for all process, voltage, and temperature conditions.

Barrantar	Cours book	Fast mode	,	Fast mode plus		Unit
Parameter	Symbol	Min.	Max.	Min.	Max.	Unit
SCL clock frequency	t _{SCL}	0	400	0	1000	kHz
Hold time (repeated) START condition. After this period, the first clock pulse is generated	t _{HD.STA}	0.6	_	0.26	_	
LOW period of the SCL clock	t _{LOW}	1.3	_	0.5	_	
HIGH period of the SCL clock	t _{HIGH}	0.6	_	0.26	_	μs
Setup time for a repeated START condition	t _{SU.STA}	0.6	 	0.26	_	
Data hold time	t _{HD.DAT}	0	_	0	_	
Data set-up time	t _{SU.DAT}	100	_	50	_	
Rise time of both SDA and SCL	t _R	20	300	_	120	ns
Fall time of both SDA and SCL	t _F	20 x (VDD / 5.5V)	300	15 x (VDD / 5.5V)	120	
Set-up time for STOP condition	t _{SU.STO}	0.6	_	0.26	_	
Bus free time between a STOP and START condition	t _{BUF}	1.3	_	0.5	_	μs
Capacity load for each bus line	Co	_	400	_	550	pF
Data valid time	t _{VD.DAT}	_	0.9	_	0.45	
Data valid acknowledge time		_	0.9	_	0.45	μs
Noise margin at LOW level for each connected device (including hysteresis)		0.054 x VDD	_	0.054 x VDD	_	V
Noise margin at HIGH level for each connected device (including hysteresis)	V _{nH}	0.054 X VDD	_	0.054 X VDD	_	V

Figure 20. I²C timing



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8.8 CSI-2 interface

8.8.1 DC specification

The DC specifications are evaluated by characterization for all process, voltage, and temperature conditions. They are not tested in production.

Table 17. CSI-2 interface - high-speed mode - DC specifications

Symbol	Parameter	Min	Typical	Max	Unit
V _{CMTX}	HS transmits static common-mode voltage	150	200	250	
V _{OD}	HS transmits differential voltage (1)	140	200	270	mV
V _{OHHS}	HS outputs high voltage (1)	_	_	360	
Z _{OS} (2)	Single-ended output impedance		50	62.5	Ω

^{1.} Value when driving into load impedance anywhere in the ZID range (80-125 Ω)

Table 18. CSI-2 interface - low-power mode - DC specifications

Symbol	Parameter	Min	Typical	Max	Unit
V _{OH}	Output high-level	1.1	1.2	1.3	V
V _{OL}	Output low-level	-50	_	50	mV
Z _{OLP}	Output impedance of LP transmitter	110	_	_	Ω

8.8.2 AC specification

Table 19. CSI-2 interface - high-speed mode - AC specifications

Symbol	Parameter	Min.	Тур.	Max.	Unit
_	Data rate	250	804	1500	Mbit/s
t _{clkp}	Average data period	_	1.25	_	ns
t _r and t _f	t _f 20% - 80% rise time and fall time	100	_	0.3UI	
t _{skew}	Data-to-clock skew	-0.15UI	_	0.15UI	ps

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^{2.} Characterization data only

9 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

9.1 Packing

Tested dice are delivered as sawn dice which are reconstructed into a wafer format on UV-tape, and delivered on a metallic ring (see figure below). The frames are packed in plastic containers, each including a maximum of 13 double-spaced reconstructed wafer rings. A mapping information file is also provided for localizing dice that may have been damaged during wafer reconstruction on sticking foil.

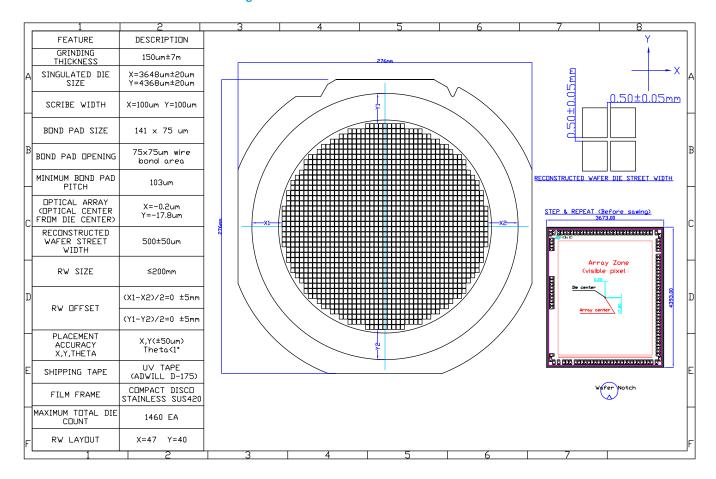


Figure 21. Reconstructed wafer information

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9.2 Storage information

Store all packing material in an appropriate indoor area. This is to prevent any dust and/or damage from the sun, external light, and physical shocks.

Keep the temperature between 15°C and 35°C.

Keep the relative humidity range between 10% and 70% maximum.

Store the reconstructed wafers under vacuum, in their original supplied sealed packing until they are used.

After the packing seal is broken, store the reconstructed wafers under nitrogen (N2) within dedicated closed shelves until they are processed.

Use the trace code to count the storage time. It is written on the package label.

The maximum storage time of the reconstructed wafer is:

- Six months from the trace code date. This is when the wafer is kept in the original sealed packing.
- One week from the trace code date. This is when the original packing seal is open.

The maximum storage time defines the maximum time that can be waited for reconstructed wafer processing. Processing may be for picking and placing, and module integration. If the maximum storage time is not respected, safe processing is not guaranteed.

Note:

For further information on reconstructed wafer specifications for visual inspection and packing, refer to the technical note TN1497.

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Revision history

Table 20. Document revision history

Date	Version	Changes
18-Apr-2024	7	First public release.

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